

# 2SC4626J

### Silicon NPN epitaxial planar type

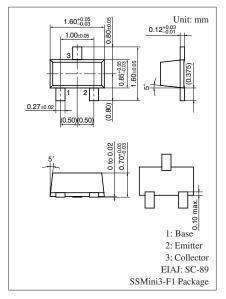
#### For high-frequency amplification

#### ■ Features

- Optimum for RF amplification of FM/AM radios
- $\bullet$  High transition frequency  $f_{T}$
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	30	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	20	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	5	V	
Collector current	$I_C$	30	mA	
Collector power dissipation	P <sub>C</sub>	125	mW	
Junction temperature	$T_{j}$	125	°C	
Storage temperature	T <sub>stg</sub>	-55 to +125	°C	



Marking Symbol: V

### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 10 \text{ V}, I_E = 0$			0.1	μΑ
Forward current transfer ratio *	$h_{FE}$	$V_{CB} = 10 \text{ V}, I_E = -1 \text{ mA}$	70		220	_
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_E = -1 \text{ mA}, f = 200 \text{ MHz}$	150	250		MHz
Noise figure	NF	$V_{CB} = 10 \text{ V}, I_{E} = -1 \text{ mA}, f = 5 \text{ MHz}$		2.8	4.0	dB
Reverse transfer impedance	Z <sub>rb</sub>	$V_{CB} = 10 \text{ V}, I_E = -1 \text{ mA}, f = 2 \text{ MHz}$		22	50	Ω
Common-emitter reverse transfer capacitance	C <sub>re</sub>	$V_{CB} = 10 \text{ V}, I_E = -1 \text{ mA}, f = 10.7 \text{ MHz}$		0.9	1.5	pF

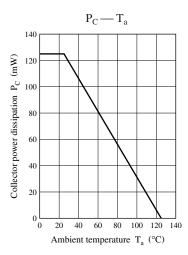
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

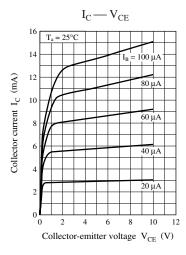
#### 2. \*: Rank classification

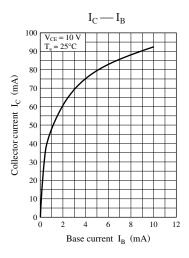
Rank	В	С	No-rank
$h_{\mathrm{FE}}$	70 to 140	110 to 220	70 to 220

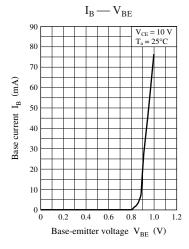
Product of no-rank is not classified and have no indication for rank.

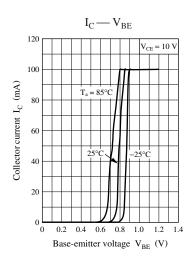
## **Panasonic**

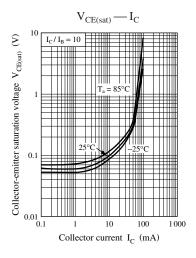


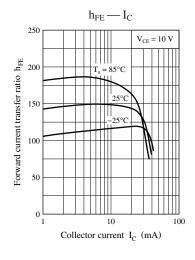


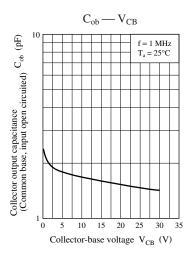












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